



Investigation of electronic coupling in semiconductor double quantum wells using coherent optical two-dimensional Fourier transform spectroscopy

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ABSTRACT

We investigate electronic coupling in asymmetric semiconductor double quantum wells using a new spectroscopy method, optical two-dimensional Fourier transform (2D-FT) spectroscopy. Measurements on two samples with different barrier thicknesses show drastically different 2D-FT spectra. We compare these measurements to conventional one-dimensional four-wave-mixing measurements, highlighting the unique advantages of the 2D-FT spectroscopy. An oscillatory behavior in the intensity of the cross peaks as a function of the mixing time is observed. This oscillation is attributed to interference between different quantum mechanical pathways, and its features are determined by the non-radiative Raman coherence between dipole-forbidden states.

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1. Introduction

Double-well potentials are encountered in many areas of physics, chemistry and biology. Examples include diffusion of defects in solids, structure relaxation in glasses, inversion of ammonia molecules, and proton tunneling between DNA base pairs. Epitaxially grown semiconductor double quantum wells (DQWs) provide a unique model system where electronic coupling strength and tunneling rate between the two wells can be easily and systematically varied by changing the barrier thickness. In DQWs, many intriguing phenomena, which are absent in single-well structures, arise from the competition between tunneling and recombination of electrons and holes [1–4]. Such dynamics become particularly interesting in the presence of quantum dissipation and decoherence. In addition, DQW structures are widely used in various opto-electronic devices. Electronic coupling between inter-well transitions is known to affect the electro-optical response in these structures [5]. Therefore, an improved understanding of electronic coupling in DQWs would allow

rational design of new and improved quantum-well-based opto-electronic devices.

In this paper, we use optical two-dimensional Fourier transform (2D-FT) spectroscopy to improve the understanding of electronic coupling by detecting it and qualitatively measuring the exciton coupling strength in DQWs. In addition, 2D-FT spectroscopy is capable of separating coherent coupling from incoherent relaxation processes. This capability is particularly useful in light of rising interest in semiconductor quantum devices operating solely in the coherent regime [6,7]. Prior to the development of 2D-FT spectroscopy, semiconductors were studied extensively using other forms of coherent spectroscopy [8]. We provide a comparison between 2D-FT and conventional spectroscopy methods in this paper.

Following concepts developed in nuclear magnetic resonance (NMR) spectroscopy [9], optical 2D-FT spectroscopy has been implemented to study vibrational coupling and to separate different line-broadening mechanisms in molecular systems [10–19]. More recently, this technique has been applied to study exciton correlations in semiconductor quantum wells [20–26]. It has been shown that a single two-dimensional spectrum can reveal couplings between resonances, separate quantum mechanical pathways, and distinguish the microscopic mechanisms of many-body interac-

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tions between excitons. Information about coupling and many-body contributions can be obtained by other enhancements to transient four-wave mixing, such as time-resolving the signal [27], spectrally resolving the signal [28] or measuring the full polarization resolved dynamics using dual channel spectral interferometry [29]. However, 2D-FT spectra provide clearer separation of different contributions and identification of the many-body contributions, particularly in complex situations, such as the one studied here.

Optical 2D-FT spectroscopy is still in an early stage of development. New understanding of the technique itself may be obtained by studying DQWs with engineered energy bands. For example, the conduction or valence subbands of DQWs can be brought into resonance by applying an electric field along the growth direction of the quantum well. It is then possible to initiate enhanced coherent oscillations of electron, hole or exciton wavepackets [30]. Such studies may show how wavepacket oscillations are manifested in 2D-FT spectra. This has implications for interpreting recent experiments aimed at understanding the ultrafast dynamics of other chemical systems, e.g., hydrogen bonds in solvents [31,32].

2. 2D Fourier transform spectroscopy

2D-FT spectroscopy is a heterodyne-detected four-wave-mixing (FWM) technique that records and correlates phase evolution during two controlled time periods, an initial evolution period, τ , and a final signal detection period, t , separated by a certain mixing (or waiting) time, T , as illustrated in Fig. 1(a). A Fourier transform with respect to τ and t yields a 2D spectrum as a function of absorption frequency ω_τ and emission frequency ω_t , respectively. The FWM signal, $S(\tau, T, t)$ is a function of three time variables. More generally, it could be transformed to a three-dimensional spectrum, $S(\omega_\tau, \omega_T, \omega_t)$. The 2D spectra we present here are slices of the general 3D spectrum corresponding to holding T constant, i.e., they are $S(\omega_\tau, T, \omega_t)$.

A peak in a 2D spectrum indicates that an oscillation at absorption frequency ω_τ during the initial time period gives rise to an oscillation at emission frequency ω_t during the third period. Coupling between resonances can be identified by the presence of cross peaks in the 2D spectrum ($\omega_\tau \neq \omega_t$). The intensity and shape of cross peaks reveal information regarding the coupling strength, dephasing dynamics, and Coulomb correlations between relevant resonances.

All discussion and measurements presented in this paper are based on the photon-echo pulse sequence, where the system evolves in conjugate frequencies during the time periods τ and t . The phase of the FWM signal is given by $e^{i(-\omega_\tau \tau + \omega_t t)}$, where the absorption frequency has the opposite sign of the emission frequency. This allows cancellation of inhomogeneous dephasing within an ensemble of static distributed oscillation frequencies. Therefore, the spectra generated by this pulse sequence are often designated as “rephasing”.

A few schematic amplitude spectra representing different scenarios are presented in Fig. 1. They correspond to (b) two independent 2-level systems, (c) two 2-level systems coupled via incoherent relaxation processes, and (d) two excited states coupled via a common ground state. Typically, coherent coupling induced cross peaks appear instantly at $T = 0$ whereas cross peaks due to incoherent relaxation processes are only observable at a finite waiting time ($T > 0$).

The experimental set-up is described in detail elsewhere [20]. Three collinearly polarized pulses are configured in the phase-matched “box” geometry. The signal is detected in the background-free direction $\mathbf{k}_s = -\mathbf{k}_a + \mathbf{k}_b + \mathbf{k}_c$. The heterodyne-detected FWM signal field is completely characterized in amplitude and phase via

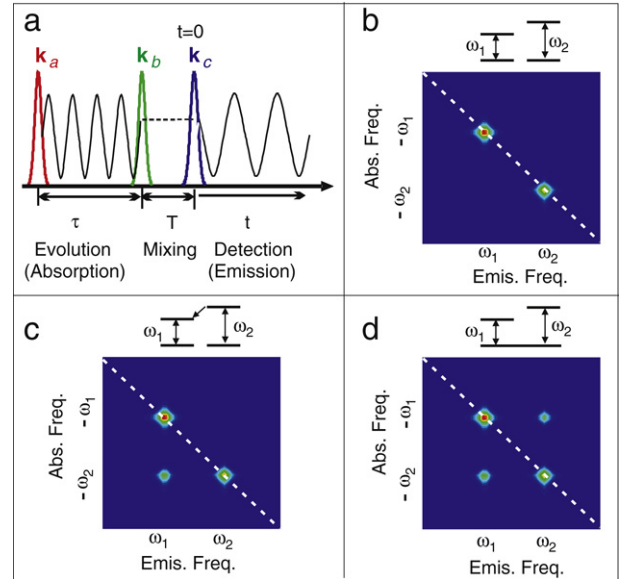


Fig. 1. (a) Pulse sequence and phase evolution of the polarization field in a typical 2D experiment. Schematic amplitude spectra for (b) two independent 2-level systems, (c) two 2-level systems coupled via incoherent relaxation processes, and (d) a 3-level system in a “V” configuration where two excited states are coupled via a common ground state. (b)–(d) are not results of rigorous simulations of a particular physical system, but schematics to represent possible ideal 2D spectra.

spectral interferometry. The FWM signal is combined collinearly with a phase-stabilized reference pulse and sent to a spectrometer. The spectral interferogram between the FWM and reference beam is measured by a CCD camera. The emission frequency, ω_t , is obtained directly via the spectrometer. The indirect absorption frequency axis, ω_τ , is obtained by Fourier transform with respect to τ . To obtain one 2D spectrum, T is fixed at a certain value, and τ is varied with a step size of ~ 1 fs for a few thousand steps. The experimental challenges mainly lie in maintaining phase stability ($\sim \frac{\lambda}{80}$) between multiple pulse pairs and step delay τ with sub-wavelength precision. We meet the requirements of having a phase stable reference and high precision stepping of τ by implementing actively stabilized interferometers [20].

3. Electronic transitions in double quantum wells

We investigated two different DQW samples, both consisting of 10 periods of alternating 8 and 9 nm GaAs quantum wells. The barrier ($\text{Al}_{0.3}\text{Ga}_{0.7}\text{As}$) thickness is 10 nm in sample A (thick barrier, weak coupling) and 1.7 nm in sample B (thin barrier, strong coupling), respectively. We calculate separately the single particle eigenstates of the conduction band, heavy-hole (hh) and light-hole (lh) valence bands, due to the one-dimensional quantum confinement in the growth direction. The single particle picture is approximate in that it neglects the Coulomb interaction between the electrons and holes. This interaction leads to the formation of excitons, or electron–hole pairs and higher order many-body effects. The binding energy of excitons depends on the materials and the thickness of quantum wells among other factors. For the quantum wells used in the current studies, the exciton binding energy is ~ 10 meV. The purpose of this calculation is not to reproduce the energetic positions of experimentally observed resonances precisely, but to qualitatively discuss possible optically allowed transitions.

We have used a self-consistent solution of the one-dimensional solution Schrödinger equation [33–35]. In the calculation, we used the following effective masses $m_e = 0.067$, $m_{hh} = 0.48$, $m_{lh} = 0.082$ and a band-gap of 1.5 eV for GaAs. We also used effe-

Fig. 2. Schematics of the DQW of 8 nm (left well) and 9 nm (right well) and calculated electron and hole wavefunctions for the case of 10 nm (a) and 1.7 nm (b) barriers. The wavefunctions are offset by the confinement energy of the state.

relative masses $m_e = 0.092$, $m_{hh} = 0.489$, $m_{lh} = 0.084$, a band-gap of 1.798 eV for AlGaAs and a conduction band offset of 232 meV.

Electron and hole wavefunctions for the two DQW structures with thin and thick barriers are plotted in Fig. 2(a) and (b), respectively. In DQWs with thick barriers, electrons and holes are mainly localized in individual quantum wells. In DQWs with thin barriers of only 1.7 nm, the wavefunctions of the electrons and light-holes become extended into both wells, while the heavy-hole wavefunction remains mostly localized in individual wells. The lowest (second lowest) electron and hole energy states correspond to those wavefunctions localized in the wide (narrow) quantum well.

The strength of an optical transition is measured by the dipole moment between ground and excited states, which is proportional to the electron and hole wavefunction overlap. We have calculated the wavefunction overlap for many possible transitions between the valence and conduction bands in the DQW structure but listed only those with large values of overlap integrals. These “bright” transitions are plotted in Fig. 3 as functions of barrier thickness.

In the thick barrier DQW, four transitions have large dipole moments. In the order of increasing energy, these transitions are $hh_1 \rightarrow e_1$, $hh_2 \rightarrow e_2$, $lh_1 \rightarrow e_1$, and $lh_2 \rightarrow e_2$. To remind the reader that the experimentally observed resonances correspond to exciton transitions, we denote these peaks as EX_{hh1e1} , EX_{hh2e2} , EX_{lh1e1} and EX_{lh2e2} , respectively.

In the thin barrier DQW, dipole moments for transitions between $hh_2 \rightarrow e_1$ and $hh_1 \rightarrow e_2$ increase since the electron wavefunctions are extended in both wells and overlap with the heavy-hole wavefunctions. The value of the overlap integrals of these two transitions is approximately 1/3 of the other four transitions. The splitting between the two heavy-hole to conduction band transitions is small and therefore unresolved in our measurements. We tentatively assign four resonances from the lower to higher energies as $hh_1/hh_2 \rightarrow e_1$, $lh_1 \rightarrow e_1$, $hh_1/hh_2 \rightarrow e_2$ and $lh_2 \rightarrow e_2$. Again, to emphasize that experimentally observed resonances are exciton transitions, we denote these transitions as EX_{hhe1} , EX_{lh1e1} , EX_{hhe2} , EX_{lh2e2} , respectively. The accurate assignment of these resonances is difficult due to complications caused by

Fig. 3. Energy of optical transitions as a function of barrier thickness, calculated based on one-dimensional quantum confinement in the growth direction. Two transitions indicated by dotted line are only allowed when the barrier is thin and the wavefunctions become extended in both wells. Diagram at right shows the transitions between single particle states.

valence band mixing and energy shifts due to strain, which can vary from sample to sample.

4. Experimental results

We first perform measurements using traditional spectrally resolved and time-integrated FWM techniques. All data are taken at a sample temperature of 10 K. Four distinct resonances in spectrally-resolved FWM measurements are observed in both sample A and sample B. In the notation introduced above, spectrally-resolved FWM corresponds to $S(\tau = 0, T = 0, \omega_t)$. The data for sample B are shown in Fig. 4(a). We then perform time-integrated FWM measurements on sample B, where the time-integrated signal is $S_{\Pi}(\tau) = \int S(\tau, T = 0, t) dt$. A weak oscillatory signal was observed, as shown in Fig. 4(b). These oscillations may arise from macroscopic polarization interferences or quantum beats due to genuine quantum mechanical coupling [27,36,37]. Quantum beats are typically identified as spectroscopic signatures for the presence of electronic coupling. There are, however, several inherent limitations in using the beating behavior to extract information on electronic coupling. First, it is often difficult to distinguish macroscopic classical polarization interference from microscopic quantum beats. Secondly, one usually analyzes the oscillation periods to identify the energy splitting between the coupled resonances. The oscillations, however, can disappear very quickly, due to both the loss of quantum coherence and destructive interference, so that a reliable analysis of the oscillation periods is often difficult. Finally, if multiple resonances with similar splitting are present, it is almost impossible to identify which particular resonances are coupled. These limitations are demonstrated clearly in the conventional time-integrated FWM measurements, as shown in Fig. 4(b). In contrast, 2D-FT spectroscopy allows one to circumvent these limitations. As a result, we were able to establish the presence of electronic couplings and to determine the coherent or incoherent nature of these couplings between specific transitions without any ambiguity.

In DQWs with thick barriers, there are several possible coupling mechanisms between various electronic resonances. In this case, electron and hole wavefunctions are localized in individual quantum wells. No coupling is expected between exciton resonances in different quantum wells. Heavy-hole and light-hole transitions confined in the same quantum well are expected to be coupled, since the same conduction band energy level is involved. Thus one expects a spectrum similar to that shown in Fig. 1(d). Such heavy-hole and light-hole couplings in single quantum wells have been extensively studied and investigated via both conventional FWM techniques and 2D-FT

